

N-channel 40 V, 0.55 mOhm, 500 Amps continuous, standard level MOSFET in LFPAK88 using NextPowerS3 Technology 6 April 2021 Product data sheet

1. General description

500 Amp continuous current, standard level gate drive, N-channel enhancement mode MOSFET in LFPAK88 package. NextPowerS3 family using Nexperia's unique "SchottkyPlus" technology delivers high efficiency and low spiking performance usually associated with MOSFETs with an integrated Schottky or Schottky-like diode but without problematic high leakage current. NextPowerS3 is particularly suited to high efficiency applications at high switching frequencies, and also safe and reliable switching at high load-current.

2. Features and benefits

- 500 Amp continuous current capability
- LFPAK88 (8 x 8 mm) LFPAK-style low-stress exposed lead-frame for ultimate reliability, optimum soldering and easy solder-joint inspection
- Copper-clip and solder die attach for low package inductance and resistance, and high I_{D (max)} rating
- Ideal replacement for D2PAK and 10 x 12 mm leadless package types
- Qualified to 175 °C
- Meets UL2595 requirements for creepage and clearance
- Avalanche rated, 100 % tested
- Low Q_G, Q_{GD} and Q_{OSS} for high efficiency, especially at higher switching frequencies
- Superfast switching with soft body-diode recovery for low-spiking and ringing, recommended for low EMI designs
- Unique "SchottkyPlus" technology for Schottky-like switching performance and low I_{DSS} leakage
- Narrow V_{GS(th)} rating for easy paralleling and improved current sharing
- Very strong linear-mode / safe operating area characteristics for safe and reliable switching at high-current conditions

3. Applications

- Brushless DC motor control
- · Synchronous rectifier in high-power AC-to-DC applications, e.g. server power supplies
- Battery protection and Battery Management Systems (BMS)
- eFuse and load switch
- Hotswap / in-rush current management

4. Quick reference data

Table 4. Outals reference date

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	40	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	500	A
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	375	W

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. <u>5</u>		-	0.35	0.4	K/W
Static chara	acteristics						
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 13		0.33	0.47	0.55	mΩ
Dynamic ch	naracteristics						
Q _{G(tot)}	total gate charge	I_D = 25 A; V_{DS} = 32 V; V_{GS} = 10 V;		-	190	267	nC
Q _{GD}	gate-drain charge	Fig. 15; Fig. 16		-	32	65	nC
Source-drai	in diode	·					
Q _r	recovered charge	$ I_{S} = 25 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V}; \\ V_{DS} = 20 \text{ V}; \text{ T}_{j} = 25 \text{ °C} $	[2]	-	93	-	nC

[1] 500A continuous current has been successfully demonstrated during application. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] includes capacitive recovery

5. Pinning information

Table 2. Pinning information									
Pin	Symbol	Description	Simplified outline	Graphic symbol					
1	G	gate		D					
2	S	source							
3	S	source	0	G-UFTA					
4	S	source		mbb076 S					
mb	D	mounting base; connected to drain	LFPAK88 (SOT1235)						

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PSMNR55-40SSH	LFPAK88	plastic, single-ended surface-mounted package (LFPAK88); 4 leads; 2 mm pitch; 8 mm x 8 mm x 1.6 mm body	SOT1235				

7. Marking

Table 4. Marking codes	
Type number	Marking code
PSMNR55-40SSH	XH55S40S

8. Limiting values

Table 5. Limiting values

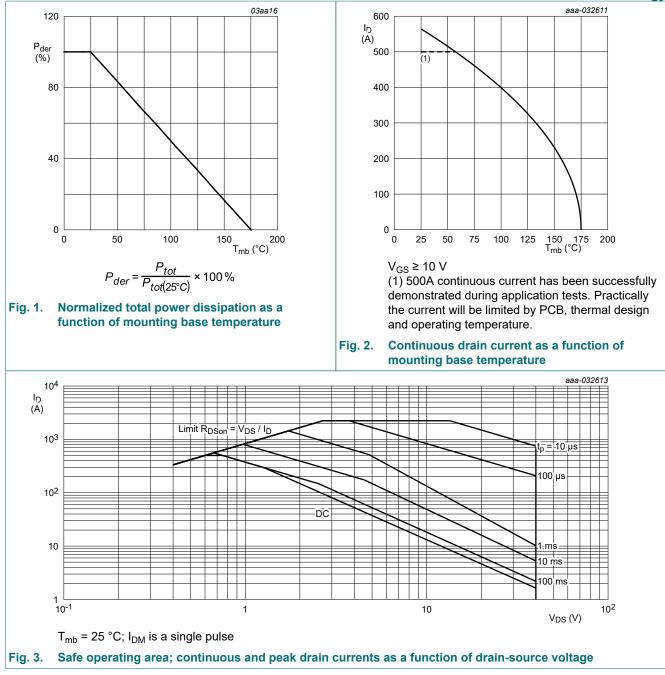
In accordance with the Absolute Maximum Rating System (IEC 60134).

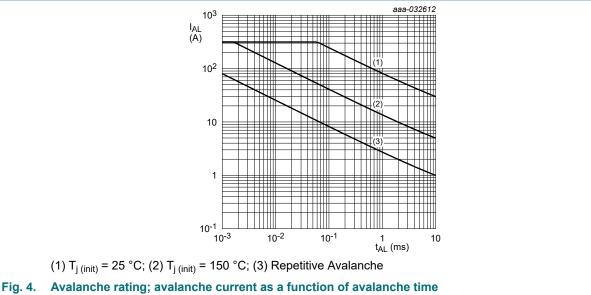
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	40	V
V _{DSM}	peak drain-source voltage	$t_p \le 20 \text{ ns}; f \le 500 \text{ kHz}; E_{DS(AL)} \le 200 \text{ nJ};$ pulsed		-	45	V
V _{DGR}	drain-gate voltage	25 °C ≤ T _j ≤ 175 °C; R _{GS} = 20 kΩ		-	40	V
V _{GS}	gate-source voltage	DC; T _j = 175 °C		-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	375	W
ID	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	500	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3		-	2237	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drain	n diode					
I _S	source current	T _{mb} = 25 °C	[1]	-	500	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	2237	А
Avalanche r	uggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$ I_D = 120 \text{ A}; \text{V}_{\text{sup}} \leq 40 \text{ V}; \text{R}_{\text{GS}} = 50 \Omega; \\ \text{V}_{\text{GS}} = 10 \text{ V}; \text{T}_{\text{j(init)}} = 25 ^{\circ}\text{C}; \text{ unclamped}; \\ \hline \text{Fig. 4} $		-	1375	mJ
I _{AS}	non-repetitive avalanche current	V_{sup} = 40 V; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; R _{GS} = 50 Ω; <u>Fig. 4</u>	[2]	-	315	A

[1] 500A continuous current has been successfully demonstrated during application. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Protected by 100% test.

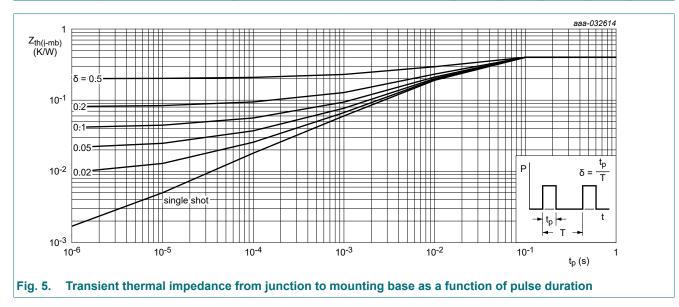




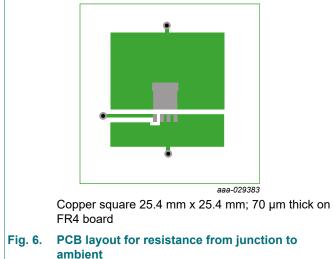


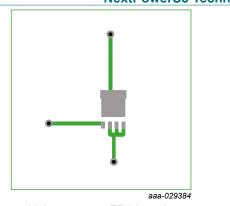
9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. <u>5</u>	-	0.35	0.4	K/W
R _{th(j-a)}	thermal resistance from	Fig. 6	-	35	-	K/W
junction to ambient	Fig. 7	-	70	-	K/W	



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70 µm thick copper on FR4 board

Fig. 7. PCB layout with minimum footprint for thermal resistance from junction to ambient

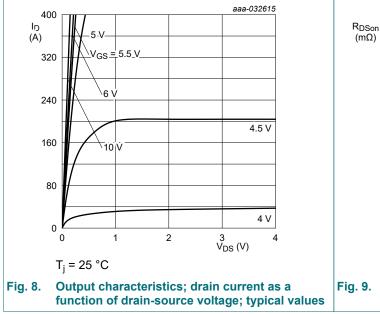
10. Characteristics

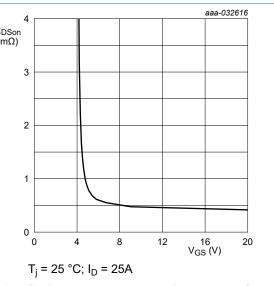
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	cteristics					
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	40	43	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	36	40	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS}=V_{GS}; T_j = 25 \text{ °C}; Fig. 11;$ Fig. 12	2.4	3	3.6	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = -55 °C; <u>Fig. 12</u>	-	-	4.3	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 175 °C; Fig. 12	1	-	-	V
$\Delta V_{GS(th)} / \Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 175 °C	-	-8.1	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 32 V; V _{GS} = 0 V; T _j = 25 °C	-	-	2	μA
		V _{DS} = 32 V; V _{GS} = 0 V; T _j = 175 °C	-	202	-	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
		V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 13	0.33	0.47	0.55	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 105 °C; Fig. 14	0.47	0.68	0.87	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 125 °C; Fig. 14	0.52	0.75	0.95	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 14	0.65	0.93	1.19	mΩ
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	0.37	0.92	2.31	Ω
Dynamic cha	racteristics	· ·	1			
Q _{G(tot)}	total gate charge	$I_D = 25 \text{ A}; V_{DS} = 32 \text{ V}; V_{GS} = 10 \text{ V};$ Fig. 15; Fig. 16	-	190	267	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V	-	96	-	nC

					ctPower		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 32 V; V _{GS} = 10 V;		-	51	77	nC
Q _{GD}	gate-drain charge	Fig. 15; Fig. 16		-	32	65	nC
C _{iss}	input capacitance	V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz;		-	15116	21162	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 17</u>		-	2718	3805	pF
C _{rss}	reverse transfer capacitance			-	544	1197	pF
t _{d(on)}	turn-on delay time	V_{DS} = 30 V; R _L = 1.2 Ω; V _{GS} = 10 V; R _{G(ext)} = 5 Ω		-	40	-	ns
t _r	rise time			-	33	-	ns
t _{d(off)}	turn-off delay time			-	117	-	ns
t _f	fall time			-	48	-	ns
Q _{oss}	output charge	V_{GS} = 0 V; V_{DS} = 25 V; f = 1 Hz; T _j = 25 °C		-	121	-	nC
Source-dra	ain diode					1	
V _{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 18</u>		-	0.79	1	V
t _{rr}	reverse recovery time	$I_{S} = 25 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$		-	62	-	ns
Q _r	recovered charge	V _{DS} = 20 V; T _j = 25 °C	[1]	-	93	-	nC
t _a	reverse recovery rise time			-	29	-	ns
t _b	reverse recovery fall time			-	24	-	ns

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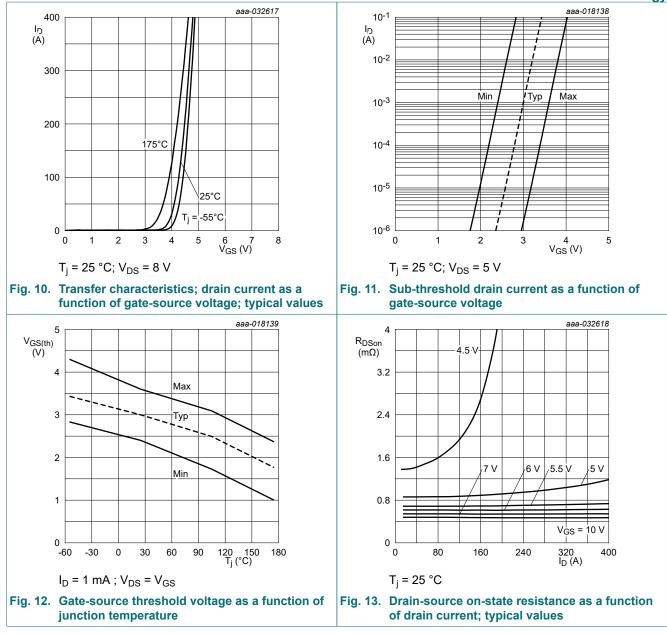
[1] includes capacitive recovery



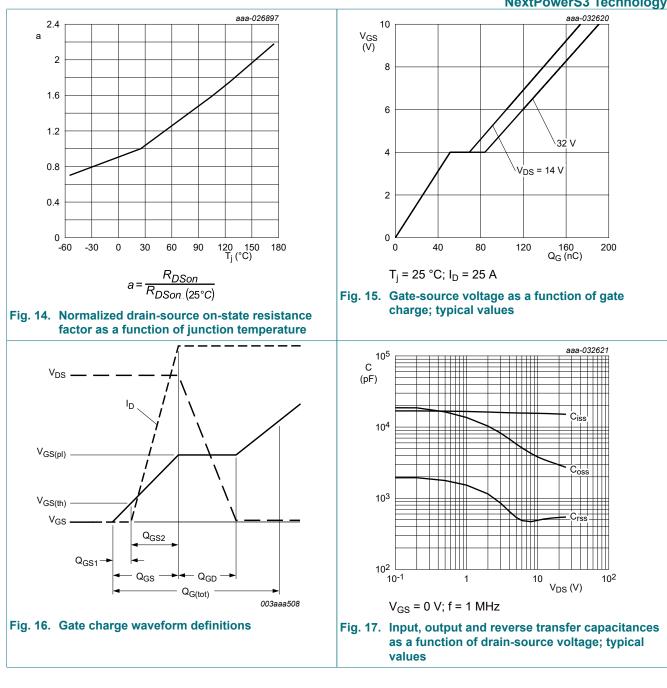


Drain-source on-state resistance as a function of gate-source voltage; typical values

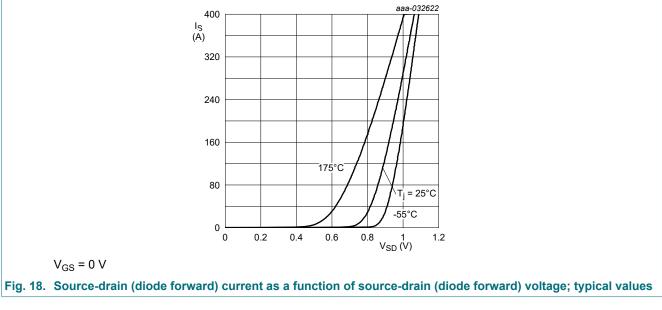




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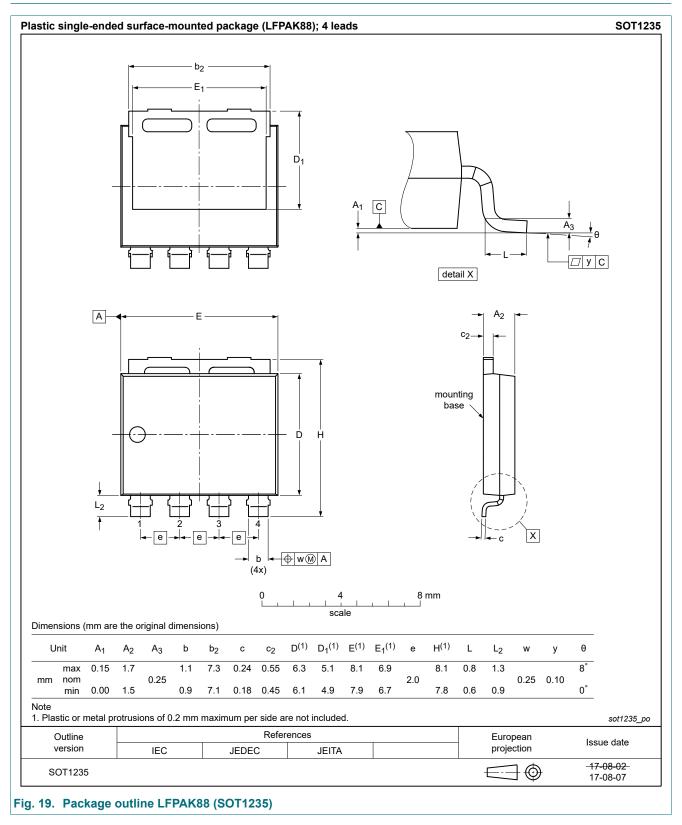


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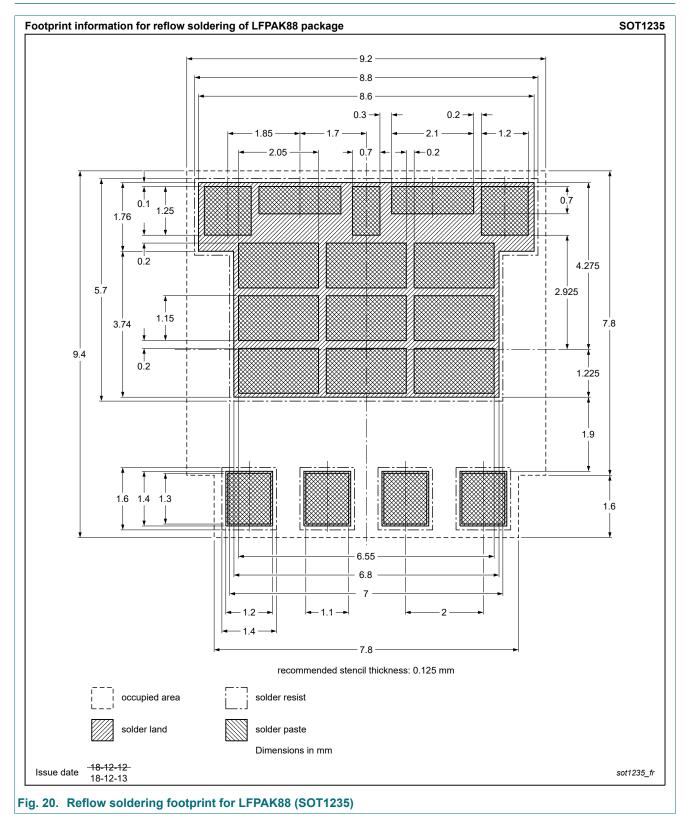
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11. Package outline



N-channel 40 V, 0.55 mOhm, 500 Amps continuous, standard level MOSFET in LFPAK88 using NextPowerS3 Technology

12. Soldering



13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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6 April 2021

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